## NSN 5961-00-901-3863



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-901-3863 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Function For Which Designed:** Amplifier **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, dc and 100.0 collector-to-emitter, resistance between base and emitter **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

## **NSN 5961-00-901-3863** Transistor - Page 2 of 2



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